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Attorney's Docket No.: 10559-587001
Intel Docket No.: P12768

AF 2812 -

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Been-Yih Jin et al. Art Unit : 2812
Serial No. : 10/081,992 Examiner : Ron E. Pompey
Filed : February 21, 2002 Assignee : Intel Corporation
Title : NON-SILICON SEMICONDUCTOR AND HIGH-K GATE DIELECTRIC
METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS

MAIL STOP AF

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REPLY

In reply to the action mailed May 21, 2003, please amend the application as indicated on the following pages. Applicant asks that all claims be allowed in view of the amendment to the claims and remarks contained on the following sheets, a total of 7 pages.

No fee is believed to be due for this Reply; however, if any fees are due, please charge them to Deposit Account No. 06-1050.

Respectfully submitted,



Paul A. Pysher
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Date: July 21, 2003

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CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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